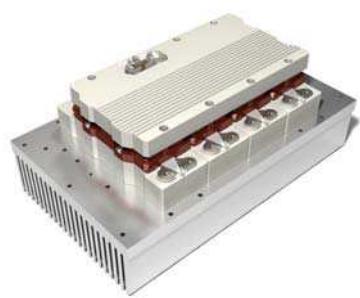


SKiiP 2403 GB172-4DFL V3



SKiiP® 3

2-pack-integrated intelligent Power System

SKiiP 2403 GB172-4DFL V3

Features

- SKiiP technology inside
- Trench IGBTs
- CAL HD diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- UL recognized File no. E63532

Typical Applications*

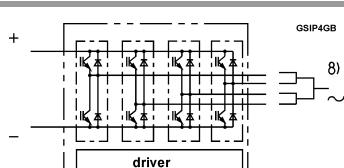
- Renewable energies
- Traction
- Elevators
- Industrial drives

Footnotes

* With assembly of suitable MKP capacitor per terminal

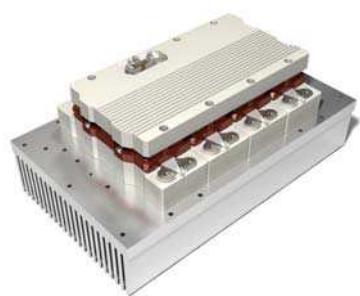
| Absolute Maximum Ratings | | $T_s = 25^\circ\text{C}$ unless otherwise specified | | |
|-------------------------------|--|---|--|-------------------|
| Symbol | Conditions | Values | | Unit |
| System | | | | |
| $V_{CC}^{1)}$ | Operating DC link voltage | 1200 | | V |
| V_{ISOL} | DC, $t = 1$ s, main terminals to heat sink | 5600 | | V |
| $I_t(\text{RMS})$ | per AC terminal, $T_{\text{terminal}} < 115^\circ\text{C}$ | 400 | | A |
| $I_{\text{max}}(\text{peak})$ | max. peak current of power section | 2500 | | A |
| I_{FSM} | $T_j = 125^\circ\text{C}$, $t_p = 10$ ms, sin 180° | 8000 | | A |
| I^2t | $T_j = 150^\circ\text{C}$, $t_p = 10$ ms, diode | 320 | | kA ² s |
| f_{out} | fundamental output frequency | 1 | | kHz |
| T_{stg} | storage temperature | -40 ... 85 | | °C |
| IGBT | | | | |
| V_{CES} | $T_j = 25^\circ\text{C}$ | 1700 | | V |
| I_c | $T_j = 150^\circ\text{C}$ | 2560 | | A |
| | $T_s = 25^\circ\text{C}$ | 1800 | | A |
| I_{Cnom} | | 2400 | | A |
| T_j | junction temperature | -40 ... 150 | | °C |
| Diode | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | 1700 | | V |
| I_F | $T_j = 150^\circ\text{C}$ | 2059 | | A |
| | $T_s = 25^\circ\text{C}$ | 1400 | | A |
| I_{Fnom} | | 1800 | | A |
| T_j | junction temperature | -40 ... 150 | | °C |
| Driver | | | | |
| V_s | power supply | 13 ... 30 | | V |
| V_{IH} | input signal voltage (high) | $V_s + 0.3$ | | V |
| V_{ISOLPD} | QPD $\leq 10\text{pC}$, PRIM to POWER | 1500 | | V |
| dv/dt | secondary to primary side | 75 | | kV/μs |
| f_{sw} | switching frequency | 7 | | kHz |

| Characteristics | | $T_s = 25^\circ\text{C}$ unless otherwise specified | | |
|----------------------|----------------------------|---|-------|------|
| Symbol | Conditions | min. | typ. | max. |
| IGBT | | | | |
| $V_{CE(\text{sat})}$ | $I_c = 1200$ A at terminal | $T_j = 25^\circ\text{C}$ | 1.9 | 2.4 |
| | | $T_j = 125^\circ\text{C}$ | 2.2 | |
| V_{CE0} | | $T_j = 25^\circ\text{C}$ | 1.00 | 1.20 |
| | | $T_j = 125^\circ\text{C}$ | 0.90 | 1.10 |
| r_{CE} | at terminal | $T_j = 25^\circ\text{C}$ | 0.75 | 0.95 |
| | | $T_j = 125^\circ\text{C}$ | 1.1 | 1.3 |
| $E_{on} + E_{off}$ | $I_c = 1200$ A | $V_{CC} = 900$ V | 780 | mJ |
| | $T_j = 125^\circ\text{C}$ | $V_{CC} = 1200$ V | 1150 | mJ |
| $R_{th(j-s)}$ | per IGBT switch | | 0.013 | K/W |
| $R_{th(j-r)}$ | per IGBT switch | | 0.008 | K/W |



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SKiiP 2403 GB172-4DFL V3



SKiiP® 3

2-pack-integrated intelligent Power System

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Features

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- CAL HD diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- UL recognized File no. E63532

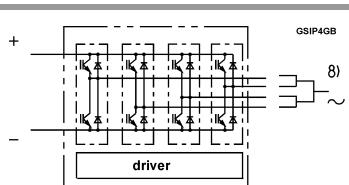
Typical Applications*

- Renewable energies
- Traction
- Elevators
- Industrial drives

Footnotes

¹ With assembly of suitable MKP capacitor per terminal

| Characteristics | | $T_s = 25^\circ\text{C}$ unless otherwise specified | | | |
|--------------------|---|---|-----------|--------|--------------------------|
| Symbol | Conditions | | min. | typ. | max. |
| Diode | | | | | |
| $V_F = V_{EC}$ | $I_F = 1200 \text{ A}$ at terminal | $T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$ | 2.00 | 2.15 | V |
| V_{FO} | | $T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$ | 1.80 | 1.1 | V |
| r_F | | $T_j = 25^\circ\text{C}$ at terminal | 0.74 | 0.8 | $\text{m}\Omega$ |
| E_{rr} | $I_F = 1200 \text{ A}$ $T_j = 125^\circ\text{C}$ | $V_R = 900 \text{ V}$ $V_R = 1200 \text{ V}$ | 144 | mJ | |
| $R_{th(j-s)}$ | per diode switch | | 171 | 0.025 | K/W |
| $R_{th(j-r)}$ | per diode switch | | | 0.0246 | K/W |
| Driver | | | | | |
| V_s | supply voltage non stabilized | 13 | 24 | 30 | V |
| I_{so} | bias current @ $V_s=24\text{V}$, $f_{sw} = 0$, $I_{AC} = 0$ | 330 | | | mA |
| I_s | $k_1 = 58 \text{ mA/kHz}$, $k_2 = 0.00035 \text{ mA/A}$ | = 330 + $k_1 * f_{sw}$ + $k_2 * I_{AC}$ | | | mA |
| V_{IT+} | input threshold voltage (HIGH) | 12.3 | | | V |
| V_{IT-} | Input threshold voltage (LOW) | | 4.6 | | V |
| R_{IN} | input resistance | 10 | | | $\text{k}\Omega$ |
| C_{IN} | input capacitance | 1 | | | nF |
| t_{pRESET} | error memory reset time | 0.0122 | | | ms |
| t_{TD} | top / bottom switch interlock time | 3 | | | μs |
| t_{jitter} | jitter clock time | 125 | | | ns |
| t_{SIS} | short pulse suppression time | 0.625 | 0.7 | | μs |
| I_{TRIPSC} | over current trip level | 2450 | 2500 | 2550 | A_{PEAK} |
| T_{trip} | over temperature trip level | 110 | 115 | 120 | $^\circ\text{C}$ |
| V_{DCtrip} | over voltage trip level, | | not impl. | | V |
| System | | | | | |
| $t_{d(on)}IO$ | $V_{CC} = 1200 \text{ V}$ $I_C = 1200 \text{ A}$ $T_j = 25^\circ\text{C}$ | turn on propagation delay time | 1.4 | | μs |
| $t_{d(off)}IO$ | | turn off propagation delay time | 1.4 | | μs |
| $R_{th(r-a)}$ | | | 0.0286 | | K/W |
| $R_{CC+EE'}$ | terminal to chip, $T_s = 25^\circ\text{C}$ | 0.13 | | | $\text{m}\Omega$ |
| L_{CE} | commutation inductance | 3 | | | nH |
| C_{CHC} | per phase, AC-side | 4 | | | nF |
| $I_{CES} + I_{RD}$ | $V_{GE} = 0 \text{ V}$, $V_{CE} = 1700 \text{ V}$, $T_j = 25^\circ\text{C}$ | 4.8 | | | mA |
| M_{dc} | DC terminals, SI Units | 6 | 8 | | Nm |
| M_{ac} | AC terminals, SI Units | 13 | 15 | | Nm |
| w | SKiiP System w/o heat sink | 3.1 | | | kg |
| w _h | heat sink | 8 | | | kg |



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Isolation coordination acc. to EN 50178 and IEC 61800-5-1

| | |
|---|---|
| Maximum grid RMS voltage, line-to-line, star point grounded mains | 690V+20% |
| Installation altitude for maximum grid RMS voltage, line-to-line, star point grounded mains | 2000m |
| Maximum transient peak voltage between low voltage circuit and mains | 1600V |
| Pollution degree acc. to IEC 60664-1 outside the moulded power section | 2 |
| Overvoltage cat. acc. to IEC 60664-1 for mains | III |
| Basic isolation | between heat sink and mains; between low voltage circuit and mains |
| Protection level acc. to IEC 60529 | IP00 |

Environmental conditions acc. to IEC 60721

| | Storage | Transportation | Operation stationary use at weather protected locations | Operation - ground vehicle installations | Operation - ship environment |
|--|---------|----------------|--|--|------------------------------------|
| Climatic conditions | 1K2 | 2K2 | 3K3 ₍₁₎ | 5K1 | --- |
| Biological conditions | 1B1 | 2B1 | 3B1 | 5B1 | 6B1 |
| Chemically active substances (excluded: salt spray) | 1C2 | 2C1 | 3C2 | 5C2 | 6C2 |
| Mechanically active substances | 1S1 | 2S1 | 3S1 | 5S1 | 6S1 |
| Mechanical conditions | 1M3 | (4) | 3M6 ₍₂₎ | 5M3 ₍₃₎ | 6M3 |
| Contaminating fluids | --- | --- | --- | 5F1 | --- |

(1) 3K3 expanded temperatur range: -40°C/+85°C

(2) 3M7 possible, but due to mechanic load capacity of external components like DC-Link capacitors limited to 3M6

(3) 5M3 without impact from foreign bodies, stones

(4) No declaration due to customer-specific packing

SKiiP 2403 GB172-4DFL V3

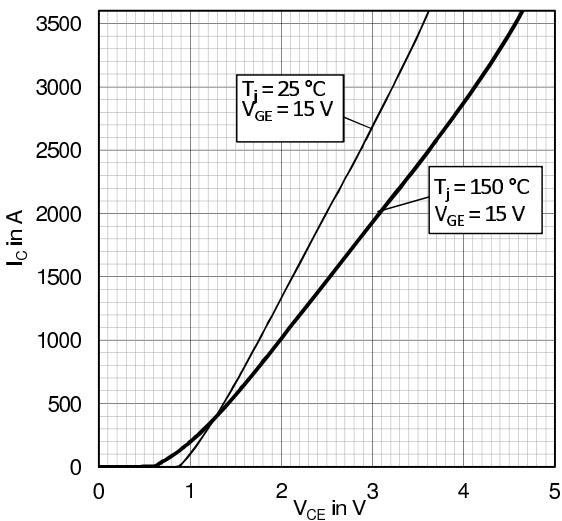


Fig. 1: Typical IGBT output characteristic

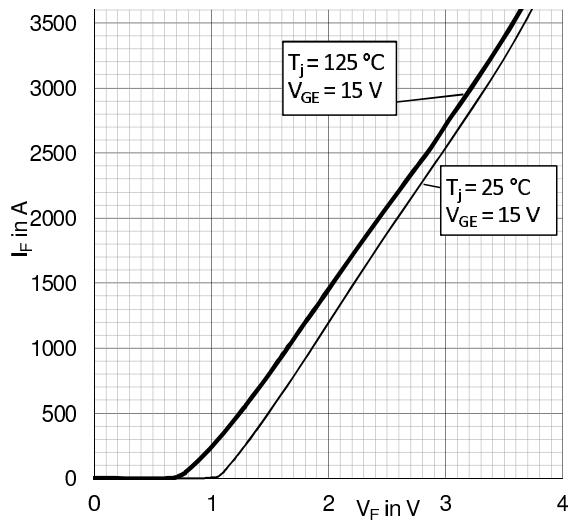


Fig. 2: Typical diode output characteristics

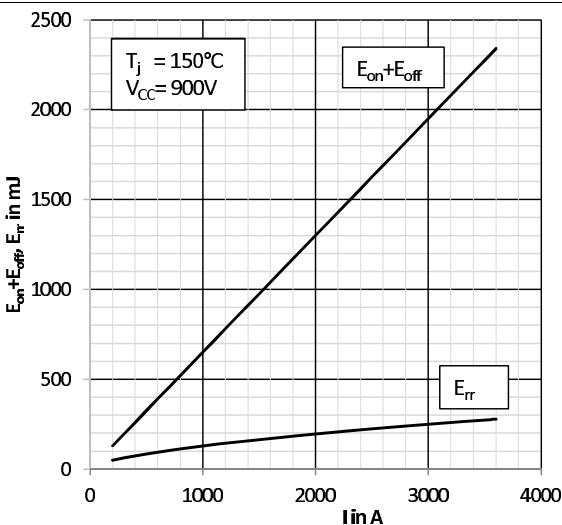


Fig. 3: Typical energy losses $E = f(I_c, V_{cc}, T_j)$

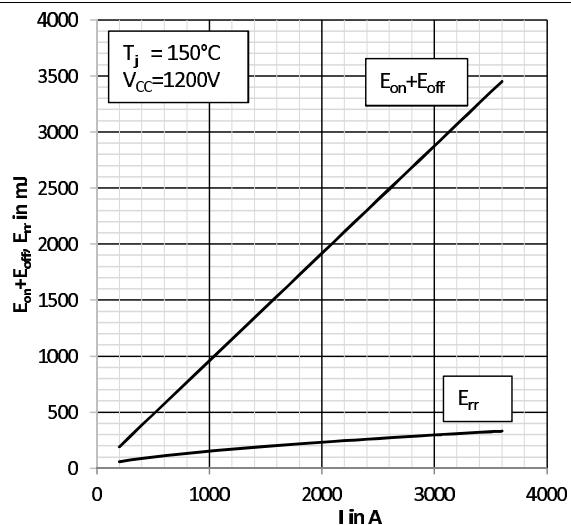


Fig. 4: Typical energy losses $E = f(I_c, V_{cc}, T_j)$

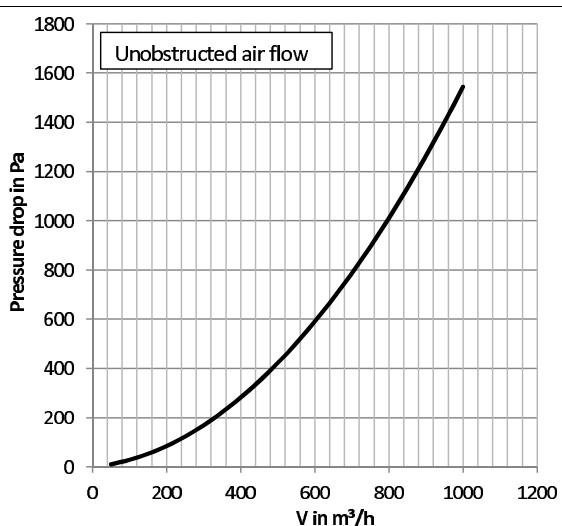


Fig. 5: Pressure drop Δp versus flow rate V

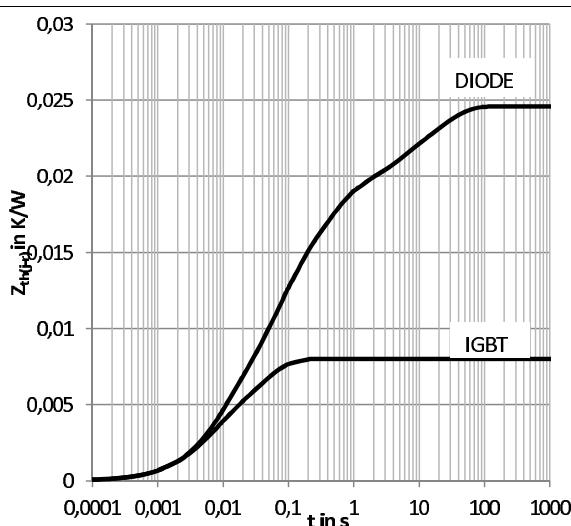


Fig. 6: Transient thermal impedance $Z_{th(j-r)}$

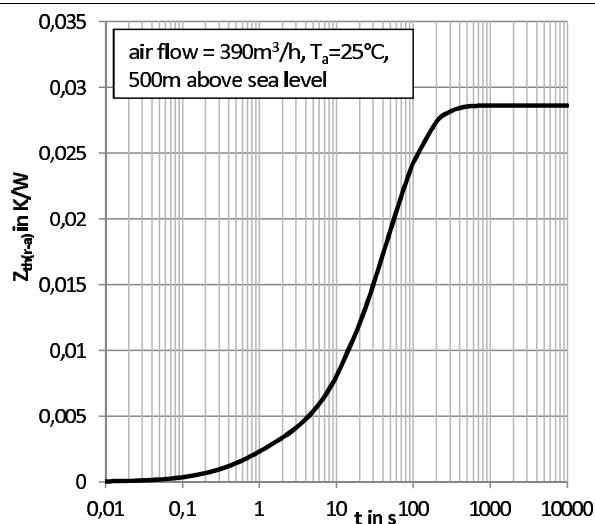


Fig. 7: Transient thermal impedance $Z_{th(r-a)}$

| | $R_{th} [K/W]$ | | | | |
|-----------------|----------------|--------|---------|--------|--------|
| | 1 | 2 | 3 | 4 | 5 |
| $Z_{th(j-r)} I$ | 0,0025 | 0,0055 | 0,0000 | 0,0000 | 0,0000 |
| $Z_{th(j-r)} D$ | 0,0051 | 0,012 | 0,0075 | 0,0033 | 0,0075 |
| $Z_{th(r-a)}$ | 0,0021 | 0,0033 | 0,0180 | 0,0052 | 0,0000 |
| | $\tau [s]$ | | | | |
| | 1 | 2 | 3 | 4 | 5 |
| $Z_{th(j-r)} I$ | 0,0040 | 0,0460 | 1,0000 | 1,0000 | 1,0000 |
| $Z_{th(j-r)} D$ | 0,0040 | 0,0160 | 0,0880 | 0,1300 | 1,300 |
| $Z_{th(r-a)}$ | 0,9000 | 20,000 | 100,000 | 170,00 | 1,0000 |

Fig. 8: Coefficients of thermal impedances

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.